



# PQMD2

NPN/PNP resistor-equipped transistors;  
R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$

4 November 2015

Product data sheet

## 1. General description

NPN/PNP double Resistor-Equipped Transistors (RET) in a leadless ultra small DFN1010B-6 (SOT1216) Surface-Mounted Device (SMD) plastic package.

## 2. Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Low package height of 0.37 mm
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

## 3. Applications

- Low current peripheral driver
- Control of IC inputs
- Replaces general-purpose transistors in digital applications
- Mobile applications

## 4. Quick reference data

Table 1. Quick reference data

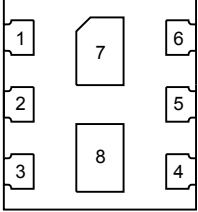
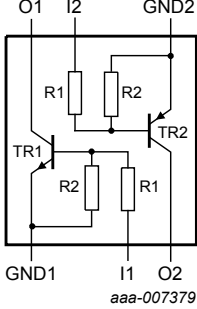
Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
<b>Per transistor; for the PNP transistor with negative polarity</b>							
V <sub>CEO</sub>	collector-emitter voltage	open base	-	-	50	V	
I <sub>O</sub>	output current		-	-	100	mA	
<b>Per transistor; for the PNP transistor with negative polarity</b>							
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	15.4	22	28.6	k $\Omega$
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	

[1] See section "Test information" for resistor calculation and test conditions.

NPN/PNP resistor-equipped transistors; R1 = 22 k $\Omega$ , R2 = 22 k $\Omega$ 

## 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1	 <p>Transparent top view <b>DFN1010B-6 (SOT1216)</b></p>	 <p>aaa-007379</p>
2	I1	input ( base) TR1		
3	O2	output (collector) TR2		
4	GND2	GND (emitter) TR2		
5	I2	input ( base) TR2		
6	O1	output (collector) TR1		
7	O1	output (collector) TR1		
8	O2	output (collector) TR2		

## 6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PQMD2	DFN1010B-6	DFN1010B-6: plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals	SOT1216

## 7. Marking

Table 4. Marking codes

Type number	Marking code
PQMD2	B 001

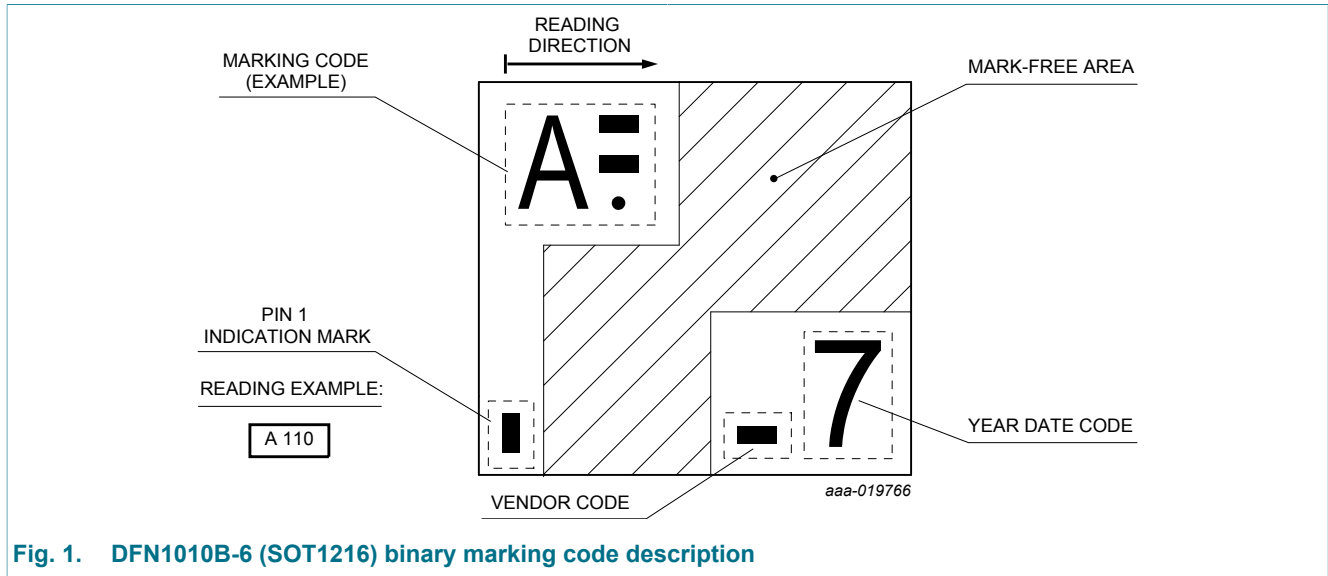


Fig. 1. DFN1010B-6 (SOT1216) binary marking code description

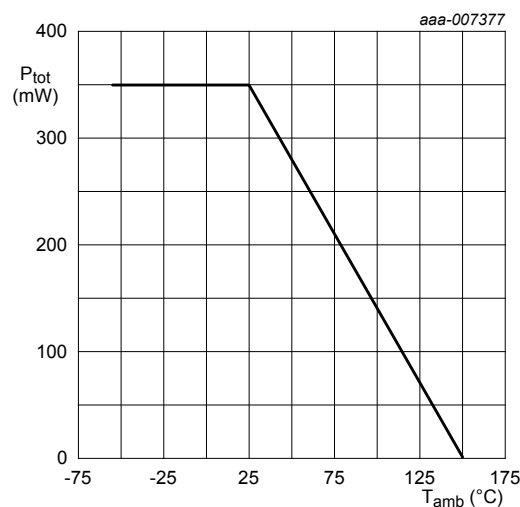
## 8. Limiting values

**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
<b>Per transistor; for the PNP transistor with negative polarity</b>						
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
V <sub>CEO</sub>	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	10	V
V <sub>I</sub>	input voltage	TR1; positive		-	40	V
		TR1; negative		-	-10	V
		TR2; positive		-	10	V
		TR2; negative		-	-40	V
I <sub>O</sub>	output current			-	100	mA
I <sub>CM</sub>	peak collector current	t <sub>p</sub> ≤ 1 ms; single pulse		-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	230	mW
<b>Per device</b>						
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	350	mW
T <sub>j</sub>	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



FR4 PCB, standard footprint

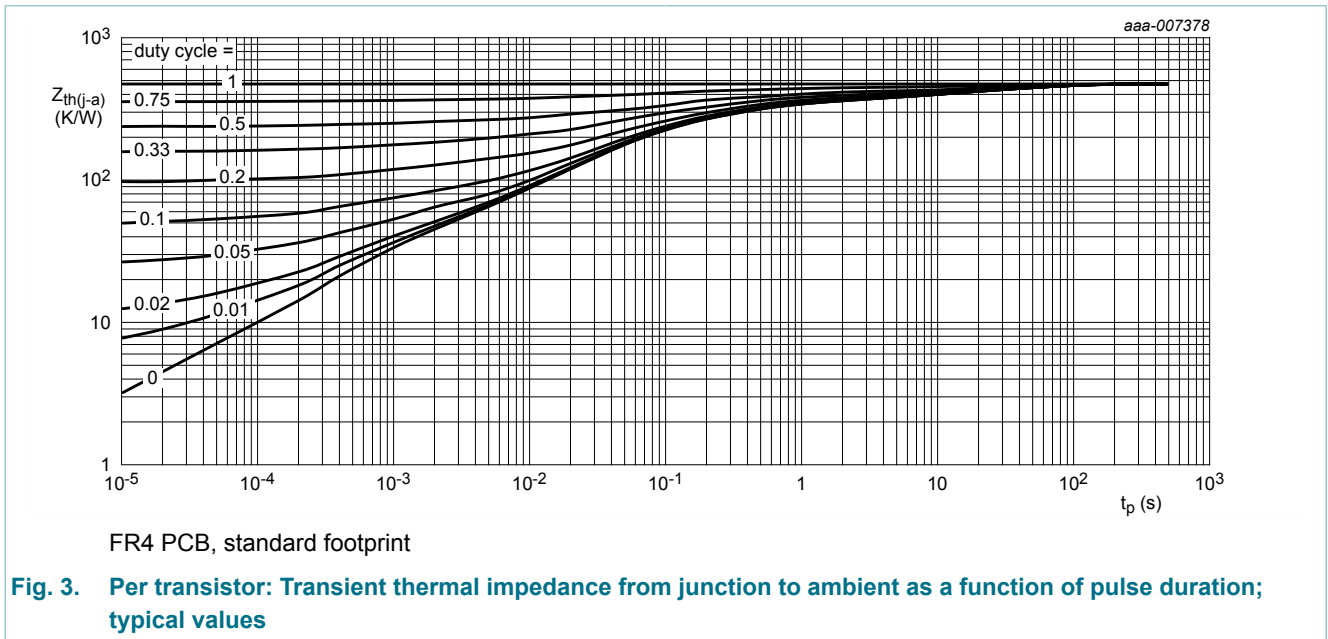
**Fig. 2. Per device: Power derating curve**

## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Per transistor</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	543	K/W
<b>Per device</b>							
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	357	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.



## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
<b>Per transistor; for the PNP transistor with negative polarity</b>							
$I_{CBO}$	collector-base cut-off current (emitter open)	$V_{CB} = 50\text{ V}$ ; $I_E = 0\text{ A}$ ; $T_{amb} = 25\text{ °C}$		-	-	100	nA
$I_{CEO}$	collector-emitter cut-off current (base open)	$V_{CE} = 30\text{ V}$ ; $I_B = 0\text{ A}$ ; $T_{amb} = 25\text{ °C}$		-	-	1	μA
		$V_{CE} = 30\text{ V}$ ; $I_B = 0\text{ A}$ ; $T_{amb} = 150\text{ °C}$		-	-	5	μA
$I_{EBO}$	emitter-base cut-off current (collector open)	$V_{EB} = 5\text{ V}$ ; $I_C = 0\text{ A}$ ; $T_{amb} = 25\text{ °C}$		-	-	180	μA
$h_{FE}$	DC current gain	$V_{CE} = 5\text{ V}$ ; $I_C = 5\text{ mA}$ ; $T_{amb} = 25\text{ °C}$		60	-	-	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = 10\text{ mA}$ ; $I_B = 0.5\text{ mA}$ ; $T_{amb} = 25\text{ °C}$		-	-	150	mV
$V_{I(off)}$	off-state input voltage	$V_{CE} = 5\text{ V}$ ; $I_C = 100\text{ μA}$ ; $T_{amb} = 25\text{ °C}$		-	1.1	0.8	V
$V_{I(on)}$	on-state input voltage	$V_{CE} = 0.3\text{ V}$ ; $I_C = 5\text{ mA}$ ; $T_{amb} = 25\text{ °C}$		2.5	1.7	-	V
R1	bias resistor 1	$T_{amb} = 25\text{ °C}$	[1]	15.4	22	28.6	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
$C_C$	collector capacitance	$V_{CB} = 10\text{ V}$ ; $I_E = 0\text{ A}$ ; $f = 1\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$ ; TR1 (NPN)		-	-	2.5	pF
		$V_{CB} = -10\text{ V}$ ; $I_E = 0\text{ A}$ ; $f = 1\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$ ; TR2 (PNP)		-	-	3	pF
$f_T$	transition frequency	$V_{CE} = 5\text{ V}$ ; $I_C = 10\text{ mA}$ ; $f = 100\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$ ; TR1 (NPN)	[2]	-	230	-	MHz
		$V_{CE} = -5\text{ V}$ ; $I_C = -10\text{ mA}$ ; $f = 100\text{ MHz}$ ; $T_{amb} = 25\text{ °C}$ ; TR2 (PNP)	[2]	-	180	-	MHz

[1] See section "Test information" for resistor calculation and test conditions.

[2] Characteristics of built-in transistor

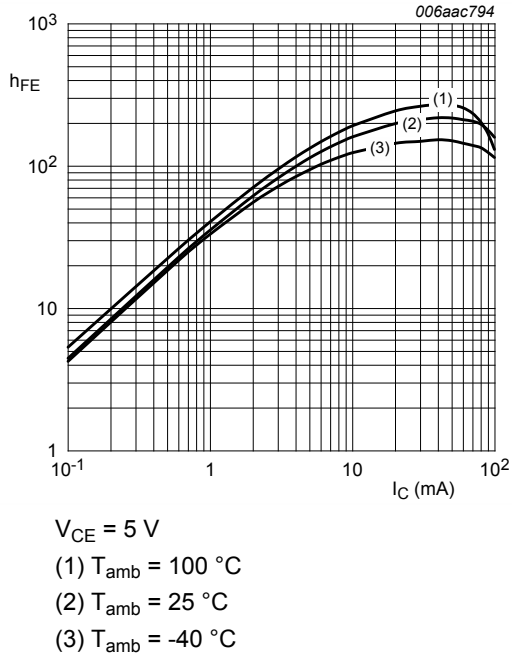


Fig. 4. NPN transistor: DC current gain as a function of collector current; typical values

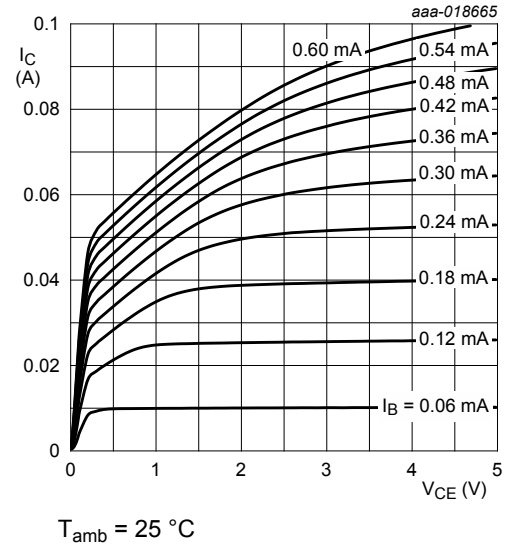


Fig. 5. NPN transistor: Collector current as a function of collector-emitter voltage; typical values

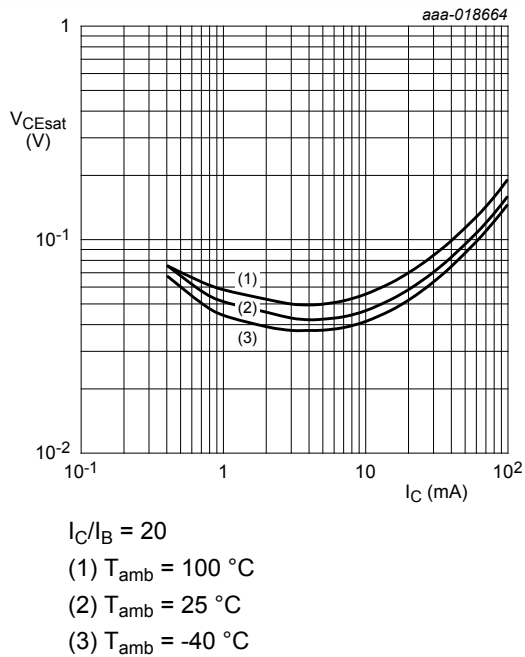


Fig. 6. NPN transistor: Collector-emitter saturation voltage as a function of collector current; typical values

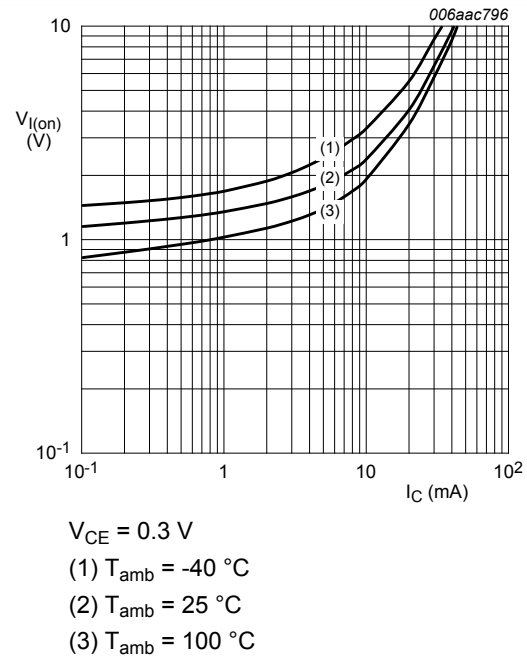
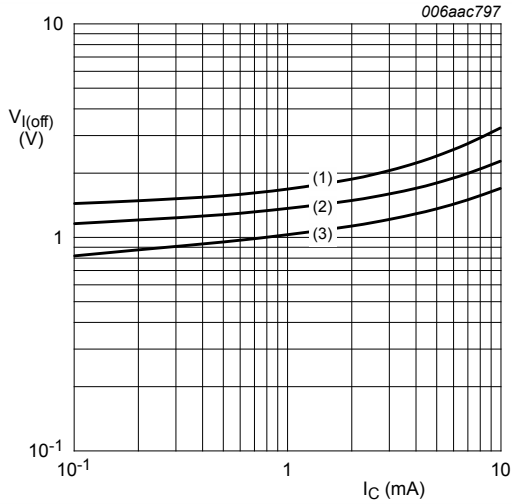
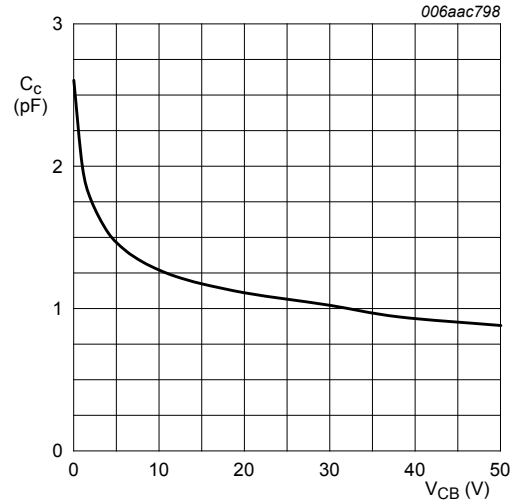


Fig. 7. NPN transistor: On-state input voltage as a function of collector current; typical values



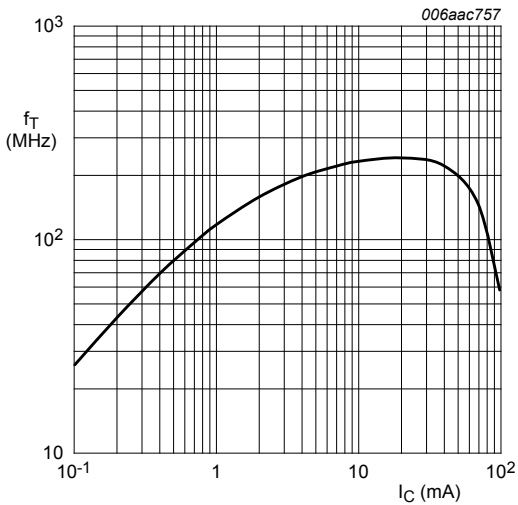
$V_{CE} = 5 \text{ V}$   
 (1)  $T_{amb} = -40 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

**Fig. 8. NPN transistor: Off-state input voltage as a function of collector current; typical values**



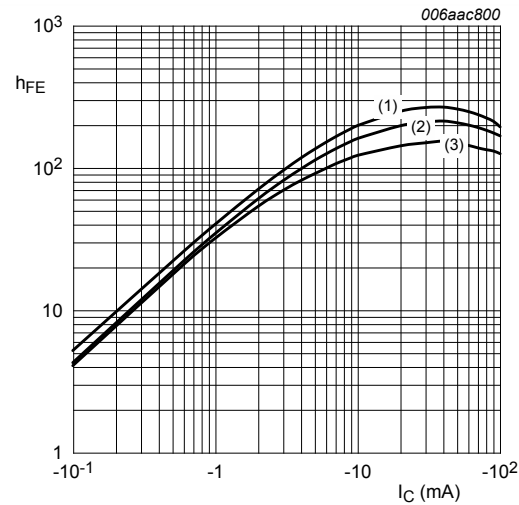
$f = 1 \text{ MHz}; T_{amb} = 25 \text{ }^\circ\text{C}$

**Fig. 9. NPN transistor: Collector capacitance as a function of collector-base voltage; typical values**



$V_{CE} = 5 \text{ V}; T_{amb} = 25 \text{ }^\circ\text{C}$

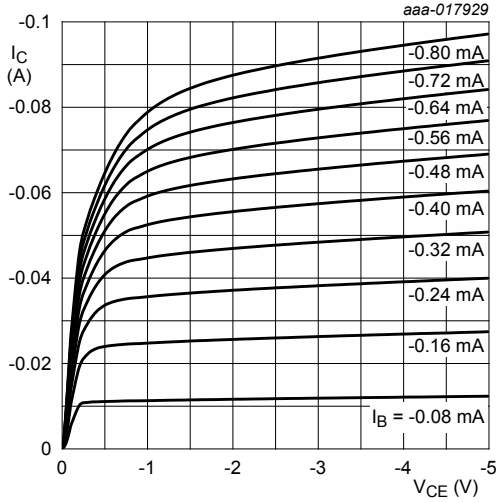
**Fig. 10. NPN transistor: Transition frequency as a function of collector current; typical values of built-in transistor**



$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = 100 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -40 \text{ }^\circ\text{C}$

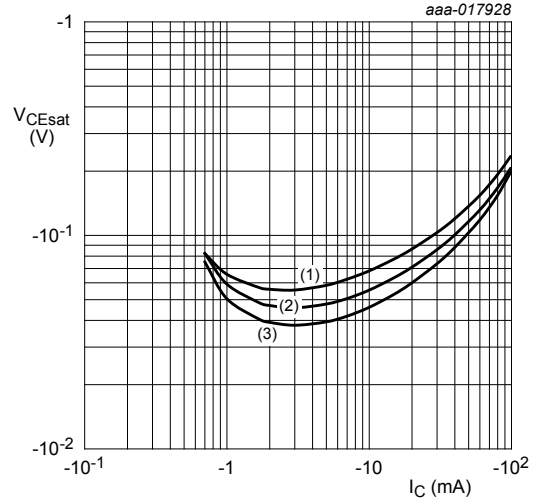
**Fig. 11. PNP transistor: DC current gain as a function of collector current; typical values**





$T_{amb} = 25\text{ °C}$

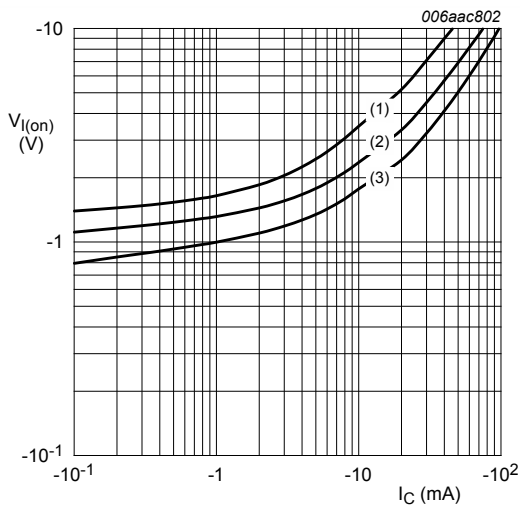
**Fig. 12. PNP transistor: Collector current as a function of collector-emitter voltage; typical values**



$I_C/I_B = 20$

- (1)  $T_{amb} = 100\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = -40\text{ °C}$

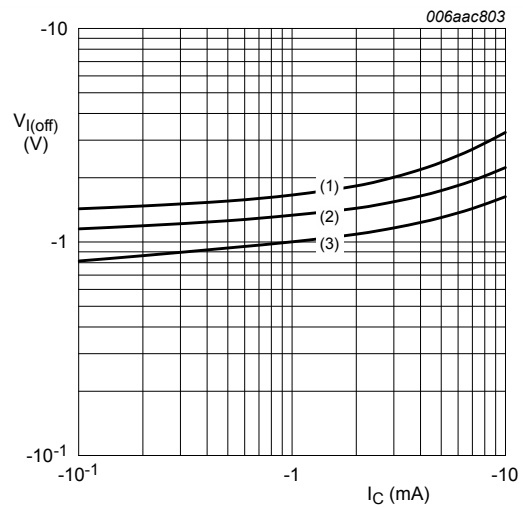
**Fig. 13. PNP transistor: Collector-emitter saturation voltage as a function of collector current; typical values**



$V_{CE} = -0.3\text{ V}$

- (1)  $T_{amb} = -40\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = 100\text{ °C}$

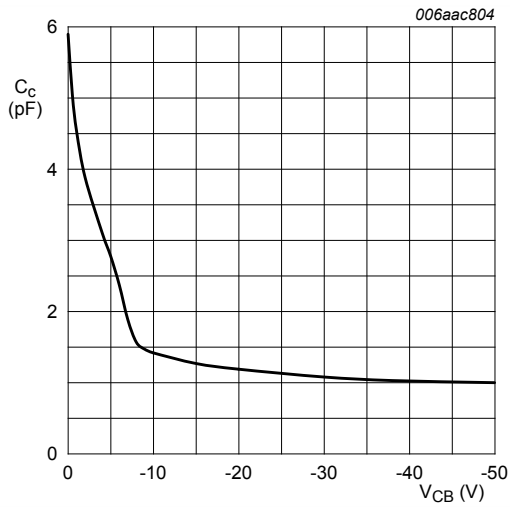
**Fig. 14. PNP transistor: On-state input voltage as a function of collector current; typical values**



$V_{CE} = -5\text{ V}$

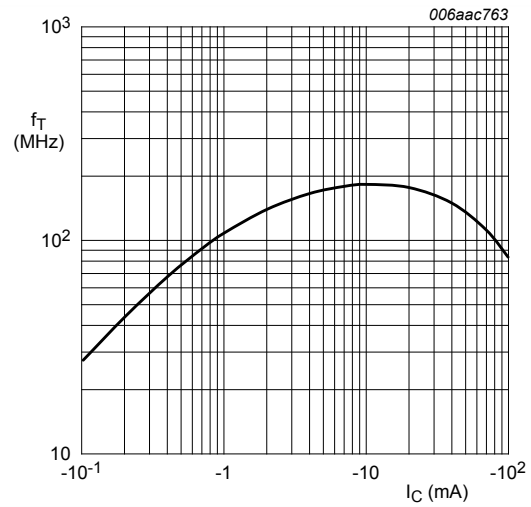
- (1)  $T_{amb} = -40\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = 100\text{ °C}$

**Fig. 15. PNP transistor: Off-state input voltage as a function of collector current; typical values**



$f = 1 \text{ MHz}; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$

**Fig. 16. PNP transistor: Collector capacitance as a function of collector-base voltage; typical values**



$V_{\text{CE}} = -5 \text{ V}; T_{\text{amb}} = 25 \text{ }^{\circ}\text{C}$

**Fig. 17. PNP transistor: Transition frequency as a function of collector current; typical values of built-in transistor**

## 11. Test information

### 11.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

### 11.2 Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I_{I2}) - V(I_{I1})}{I_{I2} - I_{I1}}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I_{I4}) - V(I_{I3})}{R1 \cdot (I_{I4} - I_{I3})} - 1$$

NPN/PNP resistor-equipped transistors; R1 = 22 kΩ, R2 = 22 kΩ

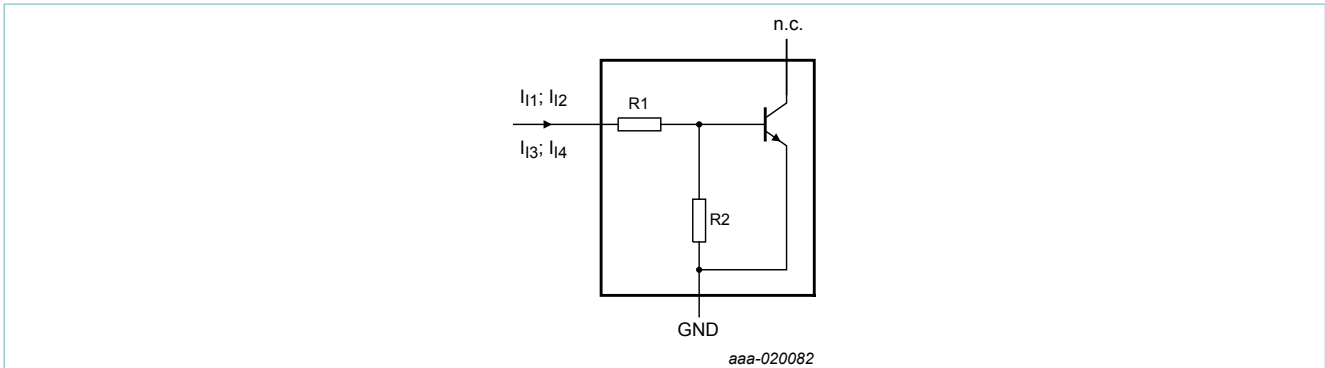


Fig. 18. NPN transistor: Resistor test circuit

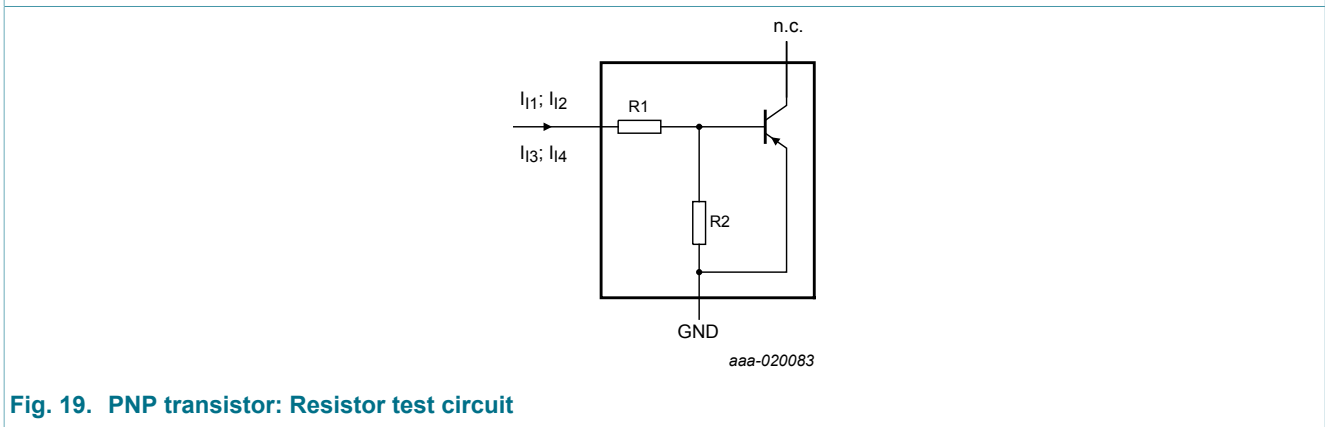


Fig. 19. PNP transistor: Resistor test circuit

### 11.3 Resistor test conditions

Table 8. Resistor test conditions

Per transistor; for the PNP transistor with negative polarity

R1 (kΩ)	R2 (kΩ)	Test conditions			
		I <sub>11</sub>	I <sub>12</sub>	I <sub>13</sub>	I <sub>14</sub>
22	22	150 μA	230 μA	-150 μA	-230 μA

## 12. Package outline

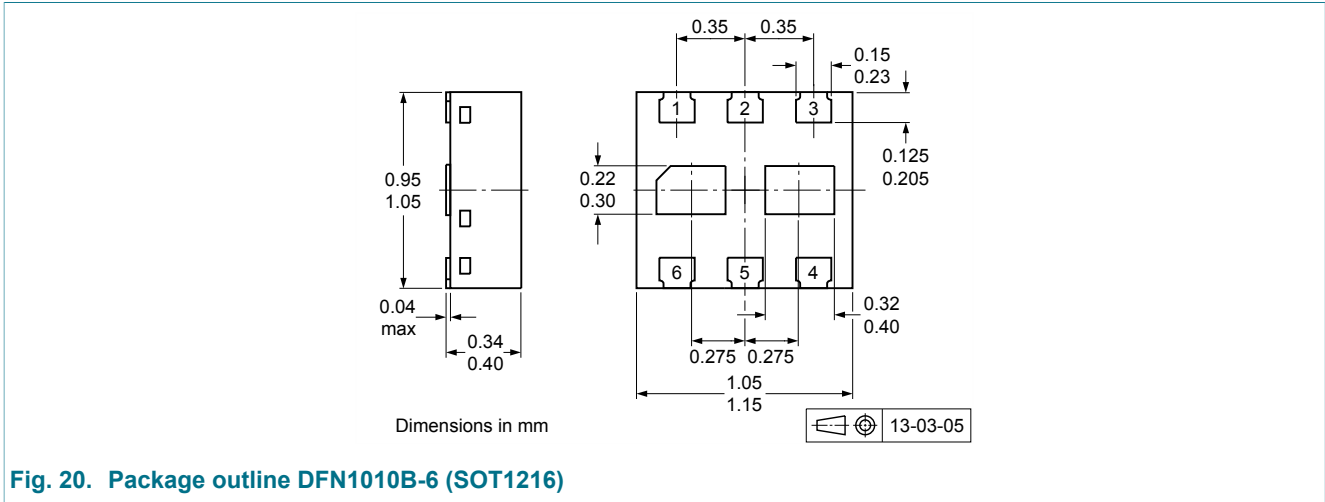


Fig. 20. Package outline DFN1010B-6 (SOT1216)

### 13. Soldering

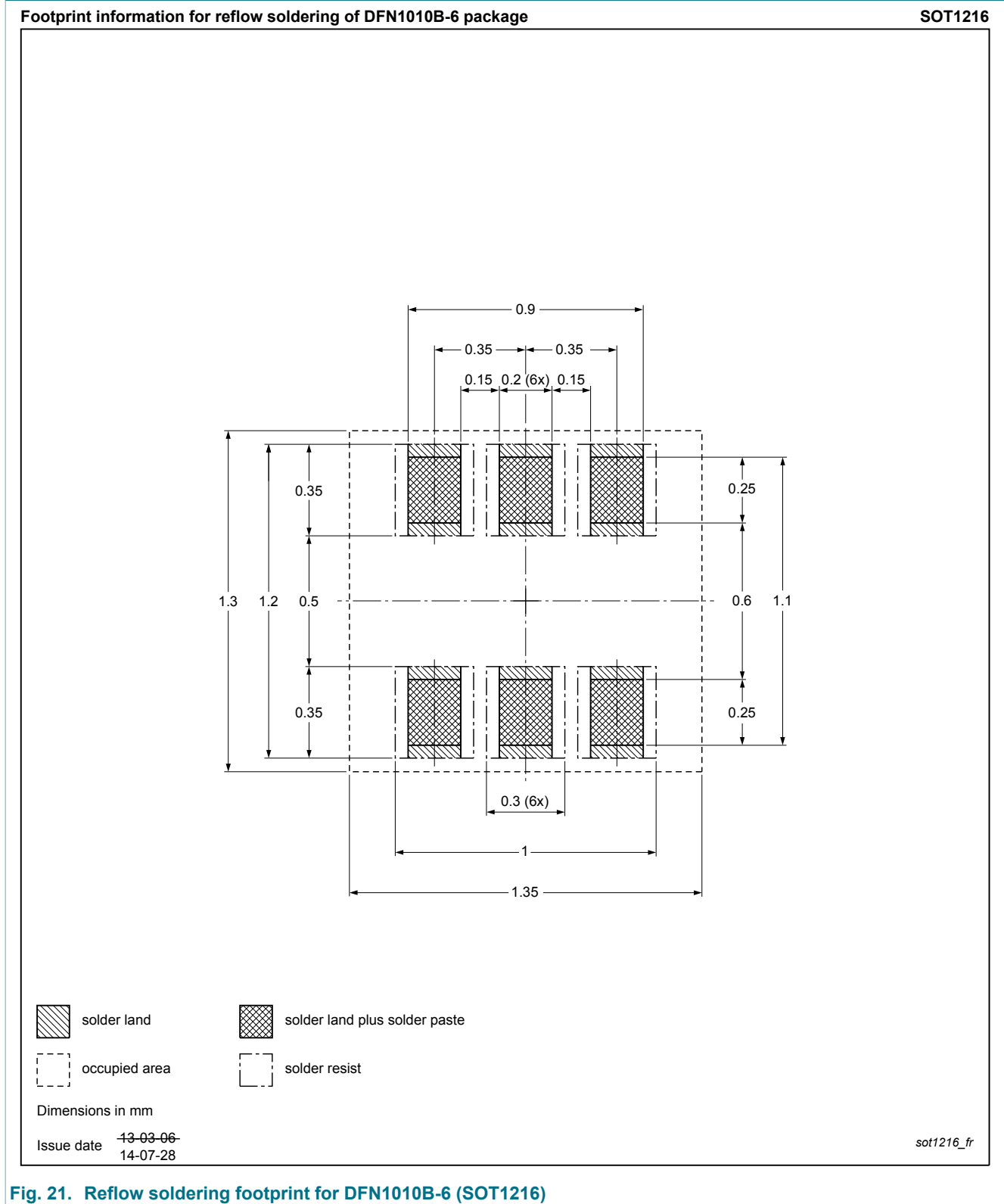


Fig. 21. Reflow soldering footprint for DFN1010B-6 (SOT1216)

## 14. Revision history

Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PQMD2 v.1	20151104	Product data sheet	-	-

## 15. Legal information

### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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